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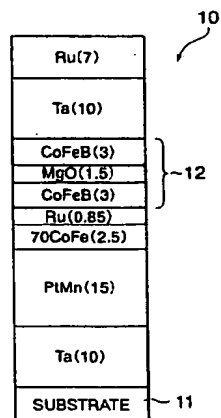
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(54) **Magnetoresistance effect device and method of production of the same**

(57) A magnetoresistance effect device including a multilayer structure having a pair of ferromagnetic layers and a barrier layer positioned between them, wherein at least one ferromagnetic layer has at least the part contacting the barrier layer made amorphous and the barrier layer is an MgO layer having a single crystal structure.

**FIG. 1****EP 1 633 007 A3**



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## EUROPEAN SEARCH REPORT

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EP 05 07 7020

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